NSN 5962-01-355-5501

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-355-5501 **Body Length:** 0.400 inches **Body Width:** 0.255 inches **Body Height:** 0.135 inches **Operating Tempurature Range:** -40.0/+85.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 5895-01-340-9279 base station, co **Features Provided:** Electrostatic sensitive and monolithic and positive outputs and erasable **Inclosure Material: Plastic Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 2 input **Current Rating Per Characteristic:** 3.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 6.5 volts power source **Time Rating Per Chacteristic:** 1000.00 nanoseconds delay **Memory Device Type: Eeprom Terminal Type And Quantity:** 8 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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